

**ASFC16G31M-51BIN vs ASFC16G31TA-51BCN Comparison**

Parameter / Part Number & result	ASFC16G31M-51BIN	ASFC16G31TA-51BCN	Comparison remark
<b>Product Description</b>	<b>eMMCv5.1 , Rev.0</b>	<b>eMMC v5.1, rev.A</b>	
<b>Capacity</b>	16GB	16GB	Same
<b>Bus Width</b>	x1 (default), x4 & x8	x1 (default) , x4 & x8	Same
<b>eMMC Version</b>	v5.1 (backward compatible with previous MMC versions)	v5.1 (backward compatible with previous MMC versions)	Same
<b>Operating Power Supply (Controller)</b>	VccQ = 1.70V ~ 1.95V or 2.7V ~ 3.6V	VccQ = 1.70V ~ 1.95V or 2.7V ~ 3.6V	Same
<b>Operating Power Supply (NAND)</b>	Vcc = 2.7V~3.6V	Vcc = 2.7V~3.6V	Same
<b>Operating Temperature</b>	Industrial (Ta = -40°C ~ 85°C)	Extended Commercial (Ta = -25°C ~ 85°C)	Same
<b>Storage Temperature</b>	-40°C ~ 85°C	-40°C ~ 85°C	Same
<b>Clock Frequency</b>	MMC I/F Clock: 0~200MHz (Max) MMC I/F Boot Freq: 0~52MHz	MMC I/F Clock: 0~200MHz (Max) MMC I/F Boot Freq: 0~52MHz	Same
<b>Interface Timing Mode</b>	HS200/ HS400	HS200/ HS400	Same
<b>NAND Flash Component</b>	Density: 128Gb Die:1, MLC	Density: 128Gb Die:1, TLC	Different
<b>Enhance mode support Configure pSLC mode</b>	No	Yes	Rev.A better
<b>Boot Partition 1</b>	4096KB	4096KB	Same
<b>Boot Partition 2</b>	4096KB	4096KB	Same
<b>Sequential Performance (HS400)</b>	Write: 80MB/s Read = 140MB/s	Write: 195MB/s Read =315MB/s	Comparable
<b>Active Power Consumption</b>	VCCQ = 120mA VCC = 120mA	VCCQ = 160mA VCC = 90mA	Comparable
<b>Standby Power Consumption</b>	VCCQ = 600uA VCC = 50uA	VCCQ = 100uA VCC = 50uA	Comparable
<b>Package Type</b>	153-ball TFBGA	153-ball TFBGA	Same
<b>Package Outer Dimensions</b>	11.5 x 13 x 1.0mm	11.5 x 13 x 1.0mm	Same
<b>Package Ball pitch/matrix</b>	0.5mm pitch, 6.5mm x 6.5mm	0.5mm pitch, 6.5mm x 6.5mm	Same



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<b>Package Material</b>	Pb and Halogen Free	Pb and Halogen Free	Same
<b>Pin to Pin Compatible</b>	Yes.		